







SN54HC251, SN74HC251 SCLS132F - DECEMBER 1982 - REVISED FEBRUARY 2022

SNx4HC251 Data Selectors/Multiplexers With 3-State Outputs

1 Features

- 3-state version of 'HC151
- Wide operating voltage range of 2 V to 6 V
- High-current 3-state outputs interface directly with system bus or can drive up to 15 LSTTL loads
- Low power consumption, 80-µA max I_{CC}
- Typical $t_{pd} = 9 \text{ ns}$
- ±6-mA output drive at 5 V
- Low input current of 1 µA max
- Perform parallel-to-serial conversion
- Complementary outputs provide true and inverted data

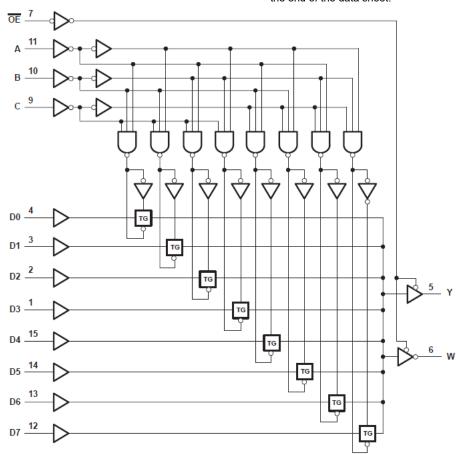
2 Description

The SNx4HC251 is a data selector/multiplexer containing full binary decoding to select 1of-8 data sources and features strobe-controlled complementary 3-state outputs.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
SN74HC251D	SOIC (16)	9.90 mm × 3.90 mm
SN74HC251DB	SSOP (16)	6.20 mm × 5.30 mm
SN74HC251N	PDIP (16)	19.31 mm × 6.35 mm
SN74HC251NS	SO (16)	6.20 mm × 5.30 mm
SN74HC251PW	TSSOP (16)	5.00 mm × 4.40 mm
SN54HC251J	CDIP (16)	24.38 mm × 6.92 mm
SNJ54HC251FK	LCCC (20)	8.89 mm × 8.45 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Pin numbers shown are for the D, DB, J, N, NS, PW, and W packages.

Functional Block Diagram



Table of Contents

1 Features	1	7.1 Overview	8
2 Description	1	7.2 Functional Block Diagram	8
3 Revision History		7.3 Device Functional Modes	9
4 Pin Configuration and Functions		8 Power Supply Recommendations	
5 Specifications	4	9 Layout	
5.1 Absolute Maximum Ratings		9.1 Layout Guidelines	
5.2 Recommended Operating Conditions(1)	4	10 Device and Documentation Support	11
5.3 Thermal Information	4	10.1 Receiving Notification of Documentation Updates	s 11
5.4 Electrical Characteristics	5	10.2 Support Resources	11
5.5 Switching Characteristics	5	10.3 Trademarks	1 1
5.6 Switching Characteristics	6	10.4 Electrostatic Discharge Caution	11
5.7 Operating Characteristics	6	10.5 Glossary	
6 Parameter Measurement Information		11 Mechanical, Packaging, and Orderable	
7 Detailed Description		Information	1 1

3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

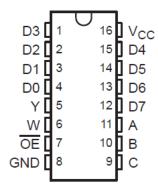
Changes from Revision E (September 2003) to Revision F (February 2022)

Page

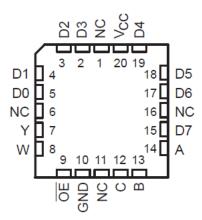
 Updated the numbering, formatting, tables, figures, and cross-refrences throughout the document to reflect modern data sheet standards......



4 Pin Configuration and Functions



J, D, DB, N, NS, or PW Package 16-Pin CDIP, SOIC, SSOP, PDIP, SO, or TSSOP Top View



NC - No internal connection

FK Package 20-Pin LCCC Top View



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I _{OK}	Output clamp current ⁽²⁾	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	V _O = 0 to V _{CC}		±35	mA
	Continuous current through V _{CC} or GN	ND .		±70	mA
TJ	Junction temperature		150	°C	
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions(1)

			SN	54HC251		SN	74HC251		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
V _{CC}	Supply voltage		2	5	6	2	5	6	V
		V _{CC} = 2 V	1.5			1.5			
V_{IH}	/ _{IH} High-level input voltage	V _{CC} = 4.5 V	3.15			3.15			V
		V _{CC} = 6 V	4.2			4.2			
	V _{CC} = 2 V			0.5			0.5		
V_{IL}	Low-level input voltage	V _{CC} = 4.5 V			1.35			1.35	V
		V _{CC} = 6 V			1.8			1.8	
V _I	Input voltage		0		V _{CC}	0		V _{CC}	V
Vo	Output voltage		0		V _{CC}	0		V _{CC}	V
		V _{CC} = 2 V			1000			1000	
Δt/Δν	Input transition rise/fall time	V _{CC} = 4.5 V			500			500	ns
		V _{CC} = 6 V			400			400	
T _A	Operating free-air temperatu	re	-55		125	-40		85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

5.3 Thermal Information

		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC ⁽¹⁾		16 PINS	16 PINS	16 PINS	16 PINS	16 PINS	UNIT
R _{θJA}	Junction-to-ambient thermal resistance	73	82	67	64	108	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

Submit Document Feedback

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST	V 00	T	_A = 25°C		SN54HC	251	SN74HC	251	UNIT
PARAMETER	CONDITIONS ⁽¹⁾	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONII
		2	1.9	1.998		1.9		1.9		
	I _{OH} = -20 μA	4.5	4.4	4.499		4.4		4.4		
V_{OH}		6	5.9	5.999		5.9		5.9		V
	I _{OH} = −6 mA	4.5	3.98	4.3		3.7		3.84		
	$I_{OH} = -7.8 \text{ mA}$	6	5.48	5.8		5.2		5.34		
		2		0.002	0.1		0.1		0.1	
	I _{OL} = 20 μA	4.5		0.001	0.1		0.1		0.1	
V_{OL}		6		0.001	0.1		0.1		0.1	V
	I _{OL} = 6 mA	4.5		0.17	0.26		0.4		0.33	
	I _{OL} = 7.8 mA	6		0.15	0.26		0.4		0.33	
I _I	$V_I = V_{CC}$ or 0	6		±0.1	±100		±1000		±1000	nA
I _{OZ}	$V_o = V_{CC}$ or 0	6		±0.01	±0.5		±10		±5	μΑ
I _{CC}	$V_I = V_{CC}$ or 0, $I_O = 0$	6			8		160		80	μΑ
C _i		2 to 6		3	10		10		10	pF

⁽¹⁾ $V_I = V_{IH}$ or V_{IL} , unless otherwise noted.

5.5 Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM	то	V (V)	T _A	= 25°C		SN54HC251	SN74HC251	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	V _{CC} (V)	MIN	TYP	MAX	MIN MAX	MIN MAX			
			2		58	205	300	256			
t _{pd} A, B, or C	A, B, or C	W or Y	4.5		21	41	60	51			
		6		19	35	51	44	no			
			2		44	195	283	244	ns		
	W or Y	4.5		17	39	57	49				
			6		15	33	48	41			
					2		30	145	210	181	
t _{en}	ŌĒ	W or Y	4.5		10	29	42	36	ns		
			6		9	25	36	31			
			2		25	195	283	244			
t _{dis}	ŌĒ	W or Y	4.5		15	39	57	49	ns		
			6		14	33	48	41			
			2		20	75	110	95			
t _t	t _t	W or Y			8	15	22	19	ns		
			6		6	13	19	16			



5.6 Switching Characteristics

over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (see Figure 6-1)

PARAMETER	FROM	то	V _{CC} (V)	TA	= 25°C		SN54HC251	SN74HC251	UNIT			
PARAMETER	(INPUT)	(OUTPUT)	VCC (V)	MIN	TYP	MAX	MIN MAX	MIN MAX	ONIT			
			2		72	300	450	375				
t _{pd} A, B, or C	W or Y	4.5		25	60	90	75					
		6		22	52	77	65	ns				
		2		59	300	450	375	115				
	Any D	W or Y	4.5		21	60	90	75				
			6		18	52	77	65				
			2		50	230	340	285				
t _{en}	ŌĒ	W or Y	4.5		17	46	68	57	ns			
			6		15	40	58	50				
			2		45	210	315	265				
t _t		W or Y	4.5		17	42	63	53	ns			
						6		13	36	53	45	

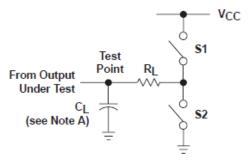
5.7 Operating Characteristics

T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C_{pd}	Power dissipation capacitance	No load	70	pF

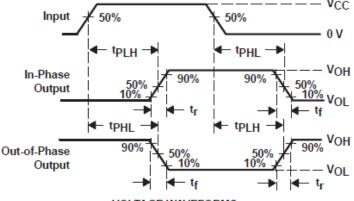


6 Parameter Measurement Information

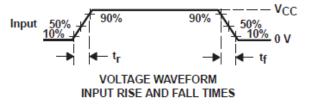


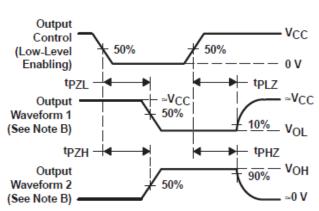
LOAD CIRCUIT

PARAMETER		R _L C _L		S 1	S2
	tpzh	1 kΩ	50 pF	Open	Closed
ten	tpzL	1 K22	or 150 pF	Closed Oper	
.	tphz	1 kΩ	50 pF	Open	Closed
^t dis	tpLZ	1 K22	50 pr	Closed	Open
t _{pd} or t _t			50 pF or 150 pF	Open	Open



VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT TRANSITION TIMES





VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- NOTES: A. C_L includes probe and test-fixture capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR ≤ 1 MHz, Z_O = 50 Ω, t_f = 6 ns, t_f = 6 ns.
 - D. The outputs are measured one at a time with one input transition per measurement.
 - E. tpl z and tpHz are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tplH and tpHL are the same as tpd.

Figure 6-1. Load Circuit and Voltage Waveforms



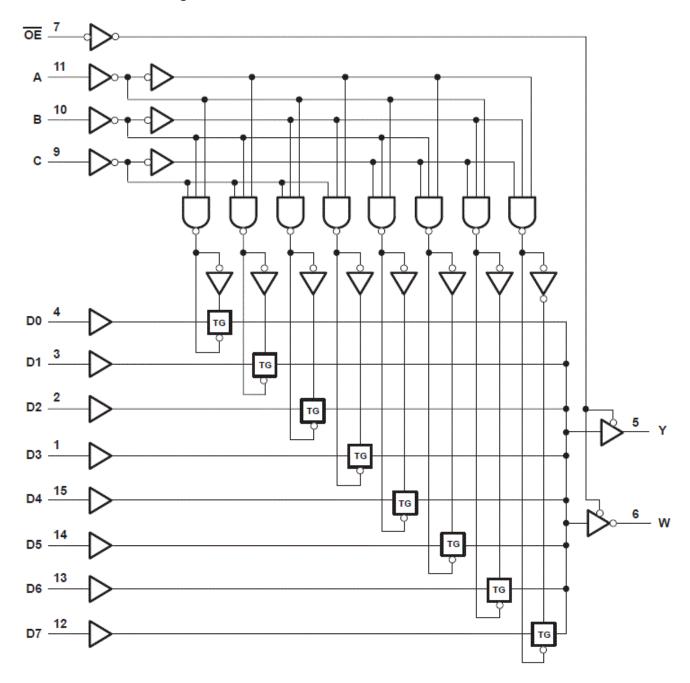
7 Detailed Description

7.1 Overview

These data selectors/multiplexers contain full binary decoding to select 1-of-8 data sources and feature strobe-controlled complementary 3-state outputs.

The 3-state outputs can interface with and drive data lines of bus-organized systems. With all but one of the common outputs disabled (in the high-impedance state), the low impedance of the single enabled output drives the bus line to a high or low logic level. Both outputs are controlled by the output-enable (\overline{OE}) input. The outputs are disabled when \overline{OE} is high.

7.2 Functional Block Diagram



Pin numbers shown are for the D, DB, J, N, NS, PW, and W packages.



7.3 Device Functional Modes

Table 7-1. Function Table⁽¹⁾

	INP	UTS		OUTPUTS			
	SELECT		ŌĒ	Υ	w		
С	В	Α	OE .	•	•••		
Х	X	X	Н	Z	Z		
L	L	L	L	D0	D0		
L	L	Н	L	D1	D1		
L	Н	L	L	D2	D2		
L	Н	Н	L	D3	D3		
Н	L	L	L	D4	D4		
Н	L	Н	L	D5	<u>D5</u>		
Н	Н	L	L	D6	D6		
Н	Н	Н	L	D7	D7		

⁽¹⁾ D0, D1 \dots D7 = the level of the respective D input.

8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.



10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



www.ti.com 11-May-2023

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
85125012A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	85125012A SNJ54HC 251FK	Samples
8512501EA	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8512501EA SNJ54HC251J	Samples
SN54HC251J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	SN54HC251J	Samples
SN74HC251DBR	ACTIVE	SSOP	DB	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC251	Samples
SN74HC251DR	ACTIVE	SOIC	D	16	2500	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC251	Samples
SN74HC251N	ACTIVE	PDIP	N	16	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC251N	Samples
SN74HC251NSR	ACTIVE	SO	NS	16	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC251	Samples
SN74HC251PWR	ACTIVE	TSSOP	PW	16	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HC251	Samples
SNJ54HC251FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	85125012A SNJ54HC 251FK	Samples
SNJ54HC251J	ACTIVE	CDIP	J	16	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8512501EA SNJ54HC251J	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

PACKAGE OPTION ADDENDUM

www.ti.com 11-May-2023

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54HC251, SN74HC251:

Catalog: SN74HC251

Military: SN54HC251

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

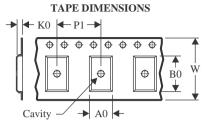
• Military - QML certified for Military and Defense Applications



www.ti.com 1-Jul-2023

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC251DBR	SSOP	DB	16	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74HC251DR	SOIC	D	16	2500	330.0	16.4	6.6	9.3	2.1	8.0	16.0	Q1
SN74HC251DR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
SN74HC251NSR	so	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
SN74HC251NSR	so	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
SN74HC251PWR	TSSOP	PW	16	2000	330.0	12.4	6.85	5.45	1.6	8.0	12.0	Q1
SN74HC251PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC251PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



www.ti.com 1-Jul-2023



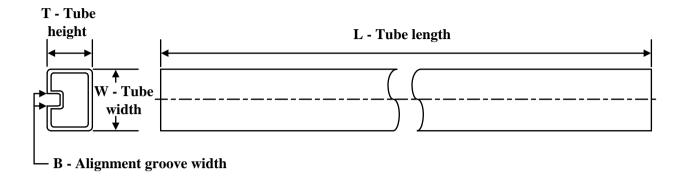
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC251DBR	SSOP	DB	16	2000	356.0	356.0	35.0
SN74HC251DR	SOIC	D	16	2500	366.0	364.0	50.0
SN74HC251DR	SOIC	D	16	2500	356.0	356.0	35.0
SN74HC251NSR	SO	NS	16	2000	356.0	356.0	35.0
SN74HC251NSR	so	NS	16	2000	356.0	356.0	35.0
SN74HC251PWR	TSSOP	PW	16	2000	366.0	364.0	50.0
SN74HC251PWR	TSSOP	PW	16	2000	356.0	356.0	35.0
SN74HC251PWR	TSSOP	PW	16	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 1-Jul-2023

TUBE

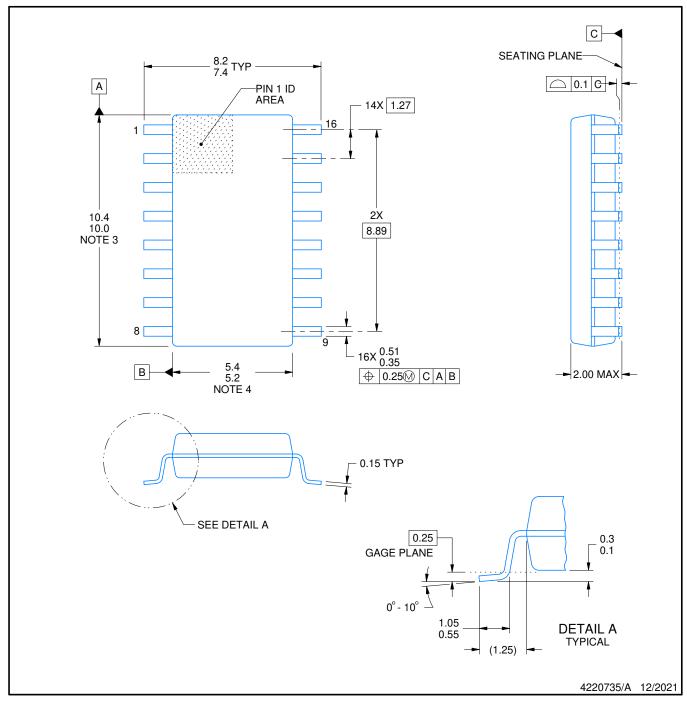


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
85125012A	FK	LCCC	20	1	506.98	12.06	2030	NA
SN74HC251N	N	PDIP	16	25	506	13.97	11230	4.32
SN74HC251N	N	PDIP	16	25	506	13.97	11230	4.32
SNJ54HC251FK	FK	LCCC	20	1	506.98	12.06	2030	NA



SOP



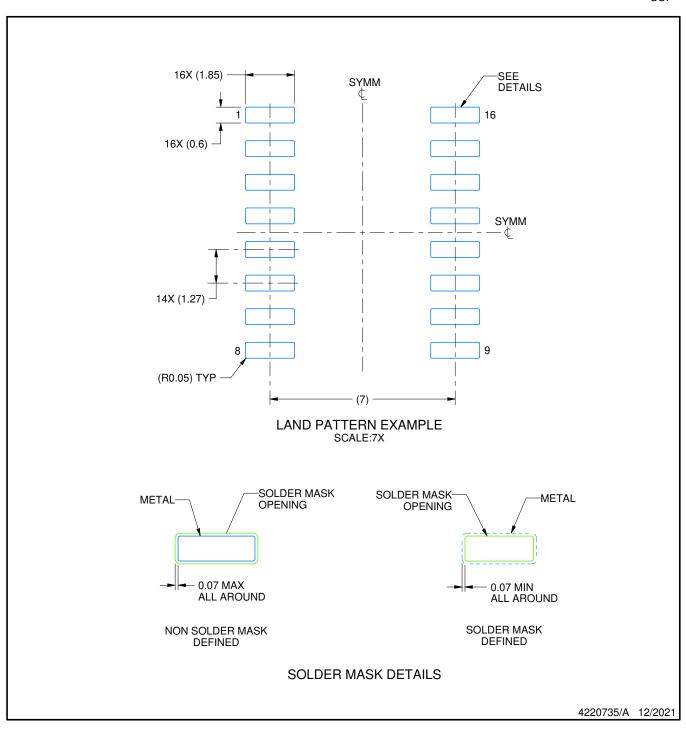
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



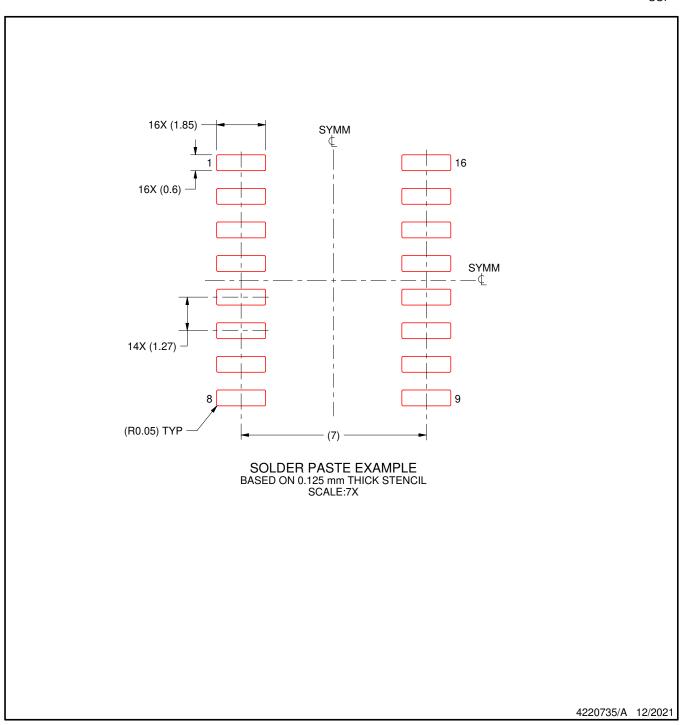
NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOP



NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



D (R-PDS0-G16)

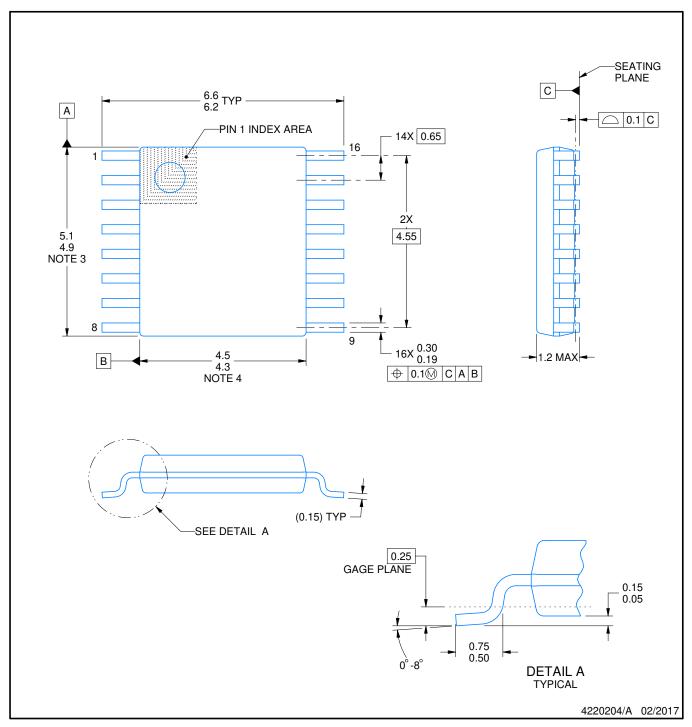
PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.





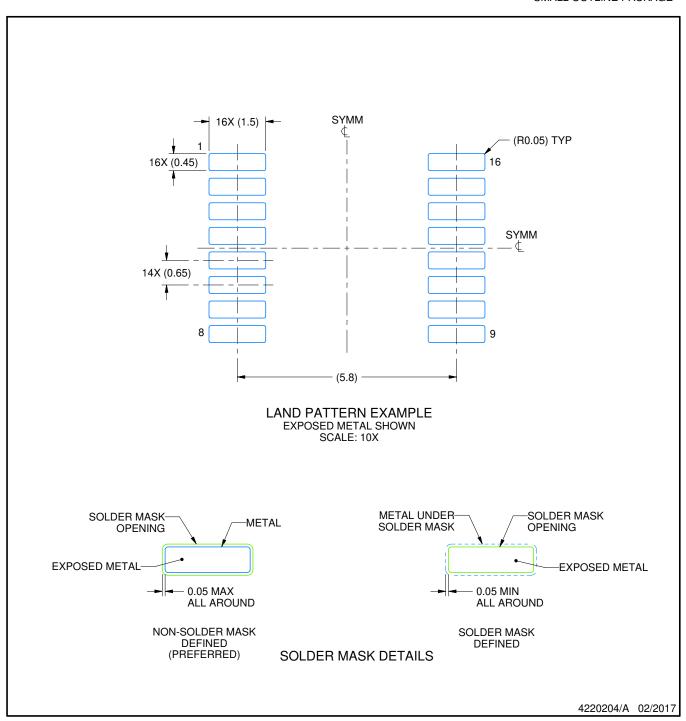


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



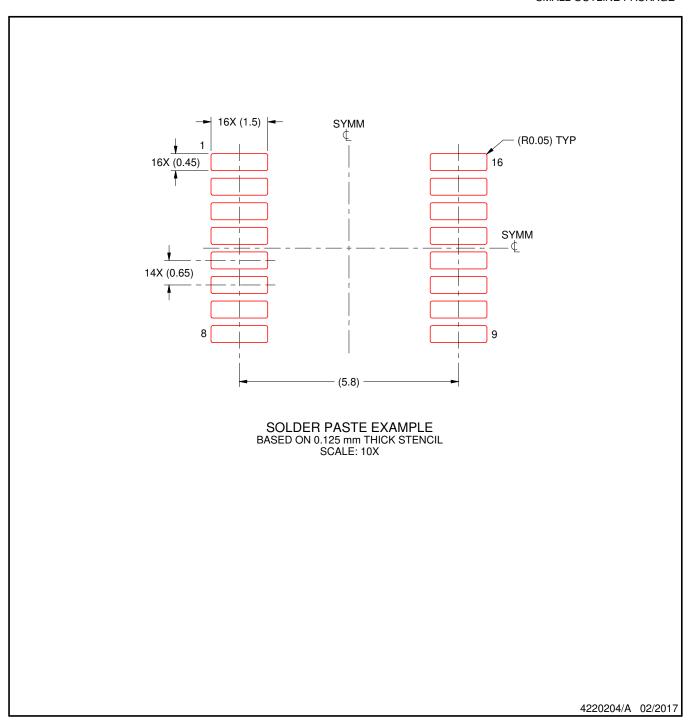


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



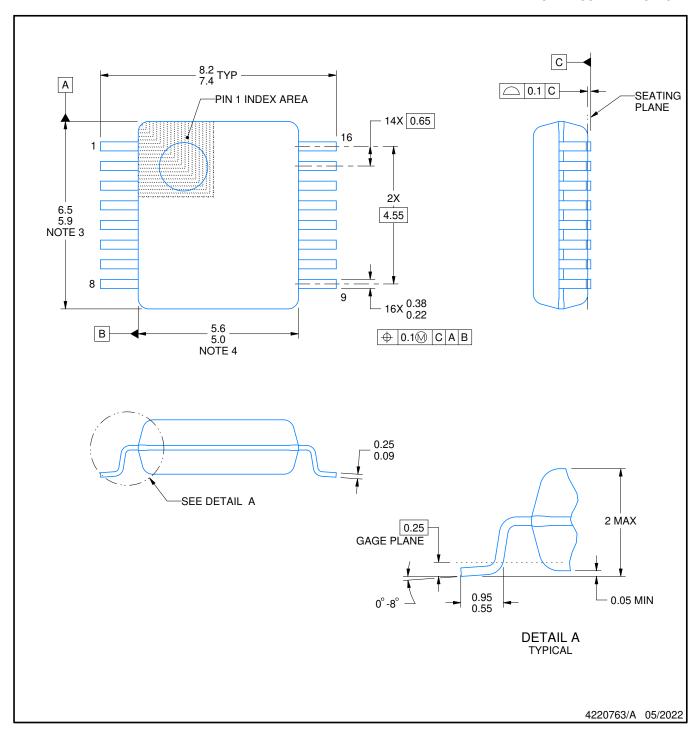


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





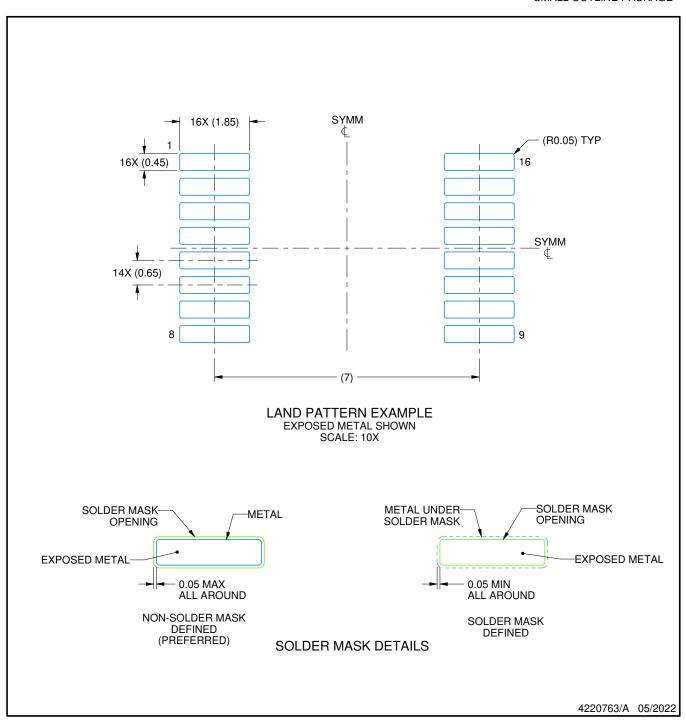


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.



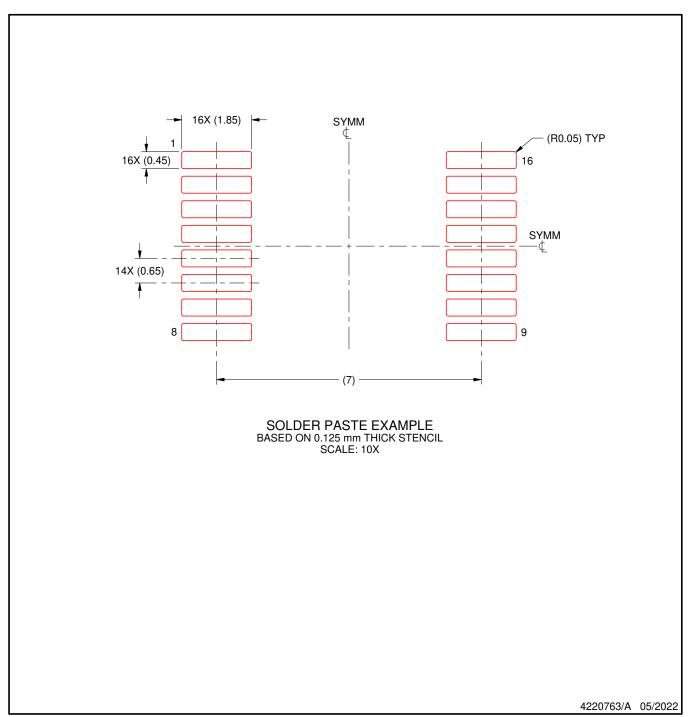


NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2023, Texas Instruments Incorporated